

## Product Overview

NSI6622 is a family of high reliability isolated dual-channel gate driver ICs which can be designed to drive power transistor up to 2MHz switching frequency. Each output could source 4A and sink 6A peak current with fast 25ns propagation delay and 5ns maximum delay matching.

The NSI6622 provides 2500Vrms isolation per UL1577 in 5\*5mm LGA13 package, 3000Vrms isolation in SOP16 (150mil) package, and 5700Vrms isolation in SOP16 (300mil) or SOP14 (300mil) package. System robustness is supported by 150kV/us typical common-mode transient immunity (CMTI).

The driver operates with a maximum supply voltage of 25V, while the input-side accepts from 2.7V to 5.5V supply voltage. Under voltage lock-out (UVLO) protection is supported by all the power supply voltage pins.

## Key Features

- Isolated dual channel driver
- Input side supply voltage: 2.7V to 5.5V
- Driver side supply voltage: up to 25V with UVLO
- 4A peak source and 6A peak sink output
- High CMTI:  $\pm 150\text{kV}/\mu\text{s}$
- 19ns typical propagation delay
- 5ns maximum delay matching
- 6ns maximum pulse width distortion
- Accepts minimum input pulse width 20ns
- Operation temperature:  $-40^\circ\text{C} \sim 125^\circ\text{C}$

## Applications

- Isolated DC-DC and AC-to-DC power supplies
- DC-to-AC solar inverters
- Motor drives and EV charging
- UPS and battery chargers

## Safety Regulatory Approvals

- UL recognition:
  - SOP16/SOP14(300mil): 5700V<sub>rms</sub> for 1 minute per UL1577
  - SOP16(150mil): 3000V<sub>rms</sub> for 1 minute per UL1577
  - LGA13: 2500V<sub>rms</sub> for 1 minute per UL1577
- DIN VDE V 0884-11:2017-01
- CSA component notice 5A
- CQC certification per GB4943.1-2011

## Device Information

Part Number	Package	Body Size
NSI6622A-DSWR	SOP16(300mil)	10.3 mm × 7.5 mm
NSI6622B-DSWR	SOP16(300mil)	10.3 mm × 7.5 mm
NSI6622C-DSWR	SOP16(300mil)	10.3 mm × 7.5 mm
NSI6622A-DSWKR	SOP14(300mil)	10.3 mm × 7.5 mm
NSI6622B-DSWKR	SOP14(300mil)	10.3 mm × 7.5 mm
NSI6622C-DSWKR	SOP14(300mil)	10.3 mm × 7.5 mm
NSI6622A-DSPNR	SOP16(150mil)	10.3 mm × 4 mm
NSI6622B-DSPNR	SOP16(150mil)	10.3 mm × 4 mm
NSI6622C-DSPNR	SOP16(150mil)	10.3 mm × 4 mm
NSI6622A-DLAR	LGA13	5 mm × 5 mm
NSI6622B-DLAR	LGA13	5mm × 5 mm
NSI6622C-DLAR	LGA13	5 mm × 5 mm

## Functional Block Diagram

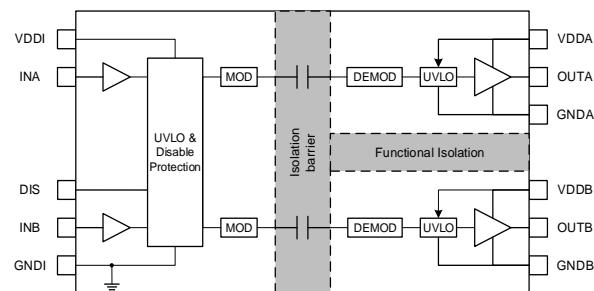


Figure 0.1 NSI6622x Block Diagram

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## 1. Pin Configuration and Functions

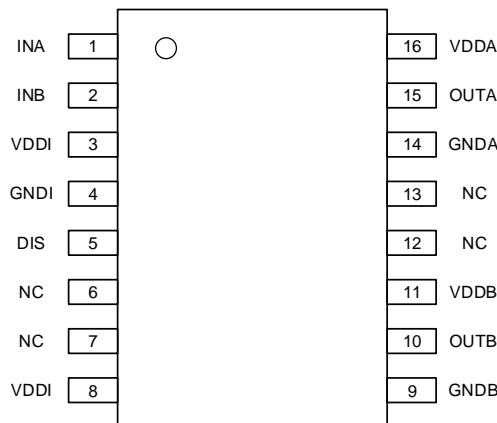


Figure 1.1 NSi6622 SOW16/SOP16 Package

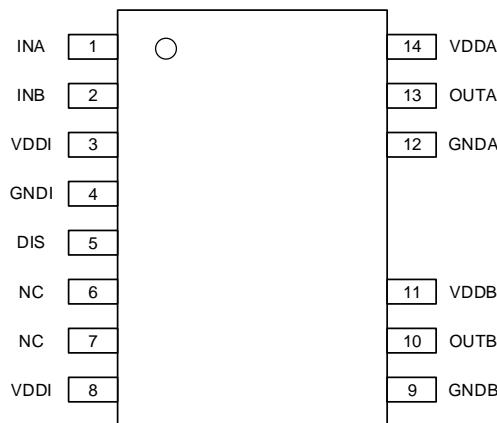


Figure 1.2 NSi6622 SOW14 Package

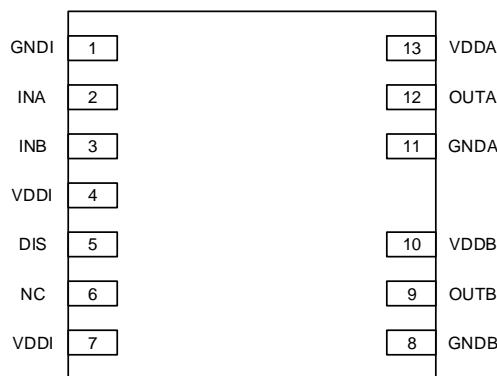


Figure 1.3 NSi6622 SOW16 Package

Table 1.1 NSi6622 Pin Configuration and Description

<i>PIN NO.</i>			<i>SYMBOL</i>	<i>FUNCTION</i>
<i>LGA13</i>	<i>SOP16</i>	<i>SOP14</i>		
1	4	4	GND	Input-side ground reference.
2	1	1	INA	TTL/CMOS compatible input signal for channel A with internal pull down to GND. It is recommended to connect this pin to GND if not used.
3	2	2	INB	TTL/CMOS compatible input signal for channel B with internal pull down to GND. It is recommended to connect this pin to GND if not used.
4, 7	3, 8	3, 8	VDDI	Input-side supply voltage. It is recommended to place a bypass capacitor from this pin to GND as close as possible.
5	5	5	DISABLE	Disables the isolator inputs and driver outputs if asserted high, enables if asserted low or left open. It is recommended to connect this pin to GND if not used.
8	9	9	GNDB	Ground for output channel B
9	10	10	OUTB	Output gate driver for channel B
10	11	11	VDBB	Supply voltage for channel B
11	14	12	GNDA	Ground for output channel A
12	15	13	OUTA	Output gate driver for channel A
13	16	14	VDDA	Supply voltage for channel A
6	6,7,12 <sup>1)</sup> ,13	6,7	NC	Not connected

- 1) For SOP16(150mil) package, Pin 12 has been connected to GNDB. Suggest not to connect Pin12 with other nets.

## 2. Absolute Maximum Ratings

Parameters	Symbol	Min	Max	Unit
Input Side Supply Voltage	VDDI to GNDI	-0.3	6	V
Output Side Supply Voltage	VDDA to GNDA, VDDB to GNDB	-0.3	30	V
Input Signal Voltage	INA, INB, DIS to GNDI	-0.3	$V_{VDDI}+0.3$	V
	INA, INB, DIS to GNDI, Transient for 50ns	-5	$V_{VDDI}+0.3$	V
Output Signal Voltage	OUTA to GNDA, OUTB to GNDB	-0.3	$V_{VDDA}+0.3$ $V_{VDDB}+0.3$	V
	OUTA to GNDA, OUTB to GNDB, Transient for 200ns	-2	$V_{VDDA}+0.3$ $V_{VDDB}+0.3$	V
Channel A to Channel B Voltage	GNDA to GNDB in LGA13 package		700	V
	GNDA to GNDB in SOP16&SOW16 package		1500	V
	GNDA to GNDB in SOW14 package		1850	V
Junction Temperature	T <sub>j</sub>	-40	150	°C
Storage Temperature	T <sub>stg</sub>	-65	150	°C
Electrostatic discharge	HBM (all pins)	-4000	4000	V
	CDM	-1500	1500	V

## 3. Recommended Operating Conditions

Parameters	Symbol	Min	Max	Unit
Input Side Supply Voltage	VDDI to GNDI	3	5.5	V
Driver Side Supply Voltage	VDDA to GNDA, VDDB to GNDB	7	25	V
Input Signal Voltage	INA, INB, DIS	0	$V_{VDDI}$	V
Junction Temperature	T <sub>j</sub>	-40	150	°C
Ambient Temperature	T <sub>a</sub>	-40	125	°C

## 4. Thermal Information

Parameters	Symbol	LGA13	SOW16/SOW14	SOP16	Unit
Junction-to-ambient thermal resistance <sup>1)</sup>	R <sub>JA</sub>	209.5	97.0	150.5	°C/W
Junction-to-case(top) thermal resistance <sup>2)</sup>	R <sub>JC (top)</sub>	48.4	23.3	21.2	°C/W
Junction-to-top characterization parameter <sup>3)</sup>	Ψ <sub>JT</sub>	41.8	35.8	52.3	°C/W
Junction-to-board characterization parameter <sup>3)</sup>	Ψ <sub>JB</sub>	31.9	39.0	55.6	°C/W

- 1) Standard JESD51-3 Low Effective Thermal Conductivity Test Board (1s) in an environment described in JESD51-2a.  
 2) Standard JESD51-3 Low Effective Thermal Conductivity Test Board (1s) by transient dual interface test method described in JESD51-14.  
 3) Obtained by Simulating in an environment described in JESD51-2a.

## 5. Specifications

### 5.1. Electrical Characteristics

VDDI=3.3V or 5V, VDDA=VDDB=12V for NSI6622A/B, VDDA=VDDB=15V for NSI6622C, Ta=-40°C to 125°C. Unless otherwise noted, Typical values are at Ta=25°C

Parameter	Symbol	Min	Typ	Max	Unit	Comments
Input Side Supply						
VDDI Quiescent Current	I <sub>VDDIQ</sub>		0.75	2	mA	INA=0, INB=0
VDDI Operation Current	I <sub>VDDI</sub>		1.8		mA	Input frequency 500kHz, C <sub>OUTA/B</sub> =15pF
VDDI UVLO Rising Threshold	V <sub>VDDI_ON</sub>	2.35	2.55	2.75	V	
VDDI UVLO Falling Threshold	V <sub>VDDI_OFF</sub>	2.15	2.35	2.55	V	
VDDI UVLO Hysteresis	V <sub>VDDI_HYS</sub>		0.2		V	
Output Side Supply						
Output Side Supply Voltage	V <sub>VDDA</sub> , V <sub>VDDB</sub>			25	V	Minimum defined by UVLO
VDDA/B Quiescent Current, per Channel	I <sub>VDDAQ</sub> , I <sub>VDDBQ</sub>		1.6	2.5	mA	INA=0, INB=0, VDDx=12V for 6V,8V UVLO; VDDx=15V for 13V UVLO
VDDA/B Operation Current, per Channel	I <sub>VDDA</sub> , I <sub>VDDB</sub>		3.2		mA	100pF, 500kHz, VDDx=12V for 6V,8V UVLO; VDDx=15V for 13V UVLO
VDDA/B UVLO Rising Threshold	V <sub>VDDA_ON</sub> , V <sub>VDDB_ON</sub>	5.7	6.15	6.5	V	NSI6622A (6V)
VDDA/B UVLO Falling Threshold	V <sub>VDDA_OFF</sub> , V <sub>VDDB_OFF</sub>	5.4	5.85	6.2	V	
VDDA/B UVLO Hysteresis	V <sub>VDDA_HYS</sub> , V <sub>VDDB_HYS</sub>		0.3		V	

Parameter	Symbol	Min	Typ	Max	Unit	Comments
VDDA/B UVLO Rising Threshold	$V_{VDDA\_ON}$ , $V_{VDBB\_ON}$	8.1	8.5	8.9	V	NSI6622B (8V)
VDDA/B UVLO Falling Threshold	$V_{VDDA\_OFF}$ , $V_{VDBB\_OFF}$	7.6	8.0	8.4	V	
VDDA/B UVLO Hysteresis	$V_{VDDA\_HYS}$ , $V_{VDBB\_HYS}$		0.5		V	
VDDA/B UVLO Rising Threshold	$V_{VDDA\_ON}$ , $V_{VDBB\_ON}$	12.7	13.2	13.7	V	NSI6622C (13V)
VDDA/B UVLO Falling Threshold	$V_{VDDA\_OFF}$ , $V_{VDBB\_OFF}$	11.7	12.2	12.7	V	
VDDA/B UVLO Hysteresis	$V_{VDDA\_HYS}$ , $V_{VDBB\_HYS}$		1		V	
Input Side Characteristic						
Input Pin Pull Down Resistance, INA, INB,	$R_{INA\_PD}$ , $R_{INB\_PD}$		100		kΩ	
Input Pin Pull Down Resistance, DIS (EN)	$R_{DIS\_PD}$		100		kΩ	
Logic High Input Threshold	$V_{INA\_H}$ , $V_{INB\_H}$ , $V_{DIS\_H}$		1.7	2	V	
Logic Low Input Threshold	$V_{INA\_L}$ , $V_{INB\_L}$ , $V_{DIS\_L}$	0.8	1.1		V	
Input Hysteresis	$V_{INA\_HYS}$ , $V_{INB\_HYS}$ , $V_{DIS\_HYS}$		0.6		V	
Output Side Characteristic						
Logic High Output Voltage	$V_{VDDA}-V_{OUTA\_H}$ , $V_{VDBB}-V_{OUTB\_H}$		0.34		V	$I_{out} = 100mA$
Logic Low Output Voltage	$V_{OUTA\_L}$ , $V_{OUTB\_L}$		55		mV	$I_{out} = -100mA$
Output Sink Resistance	$R_{OUTA\_L}$ , $R_{OUTB\_L}$		0.55		Ω	$I_{out} = 100mA$
Output Source Resistance	$R_{OUTA\_H}$ , $R_{OUTB\_H}$		3.4		Ω	$I_{out} = -100mA$
Peak Output Sink Current	$I_{OUTA\_S}$ , $I_{OUTB\_S}$		6		A	
Peak Output Source Current	$I_{OUTA\_P}$ , $I_{OUTB\_P}$		4		A	

## 5.2. Switching Characteristics

VDDI=3.3V or 5V, VDDA=VDBB=12V for NSI6622A/B, VDDA=VDBB=15V for NSI6622C, Ta=-40°C to 125°C.

Parameter	Symbol	Min	Typ	Max	Unit	Comments
Minimum Pulse Width	$t_{PWmin}$		10	15	ns	$C_{OUTA/B}=0\text{ pF}$
Propagation Delay	$t_{PDHL}$ , $t_{PDLH}$	10	25	35	ns	
Pulse Width Distortion $ t_{PDLH}-t_{PDHL} $	$t_{PWD}$			6	ns	
Channel to Channel Delay Matching	$t_{DMHL}$ , $t_{DMLH}$			5	ns	
Output Rise Time (20% to 80%)	$t_R$		7	16	ns	$C_{OUTA/B}=1.8nF$ , verified by design
Output Fall Time (90% to 10%)	$t_F$		6	12	ns	$C_{OUTA/B}=1.8nF$ , verified by design
Shutdown Time from Disable True	$t_{DIS}$			40	ns	
Recovery Time from Disable False	$t_{EN}$			40	ns	

VDDI Power-up Time Delay (Time from VDDI = VDDI_ON to OUTA/B = INA/B)	$t_{start\_VDDI}$		8.5	15	us	INA or INB tied to VDDI
VDDA/B Power-up Time Delay (Time from VDDA/B = 2V to OUTA/B = INA/B)	$t_{start\_VDDA},$ $t_{start\_VDB}$		18	30	us	INA or INB tied to VDDI; $C_{OUTA/B}=1.8nF$
Common Mode Transient Immunity	CMTI	100	150		V/ns	verified by design

### 5.3. Typical Performance Characteristics

VDDI = 3.3 V, VDDA = VDBB = 12 V, TA = 25°C. Output has no load unless otherwise noted.

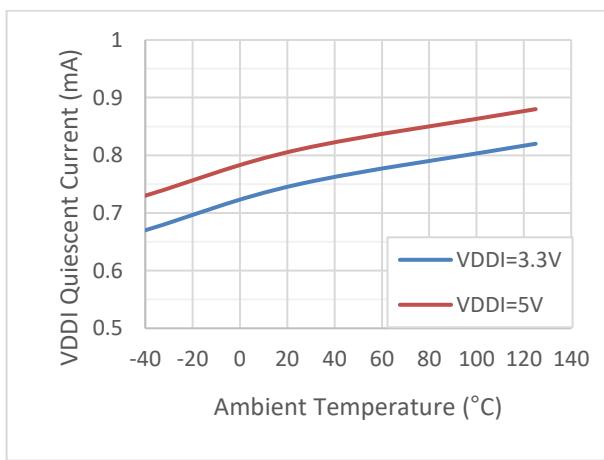


Figure 5.1 VDDI Quiescent Current vs Temperature

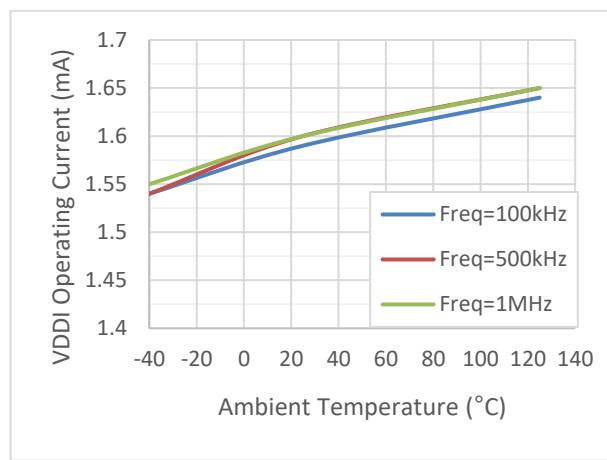


Figure 5.2 VDDI Operating Current vs Temperature

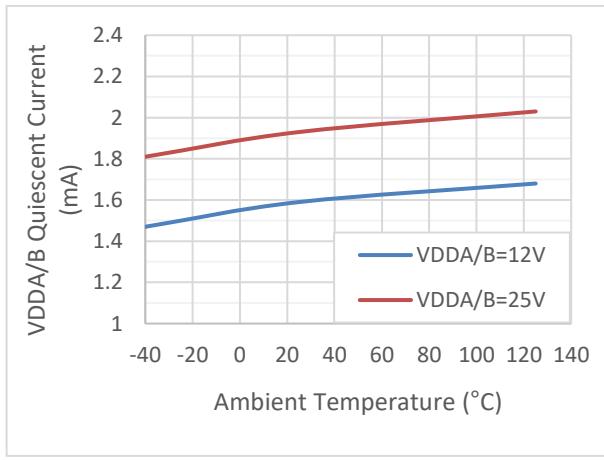


Figure 5.3 VDDA/B Quiescent Current vs Temperature

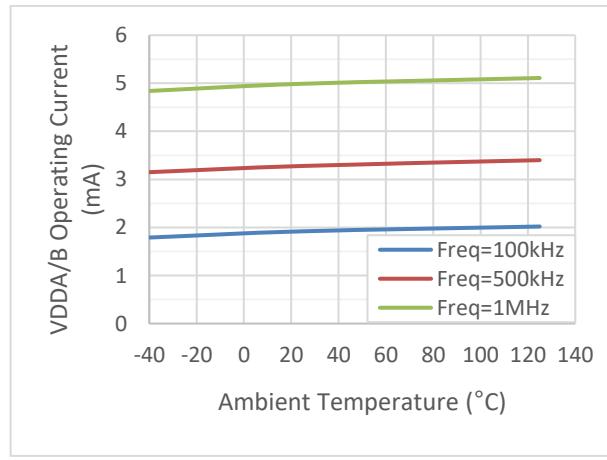


Figure 5.4 VDDA/B Operating Current vs Temperature

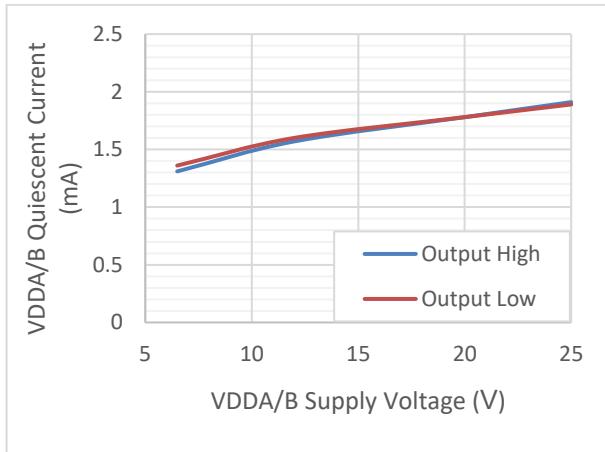


Figure 5.5 VDDA/B Quiescent Current vs Supply Voltage

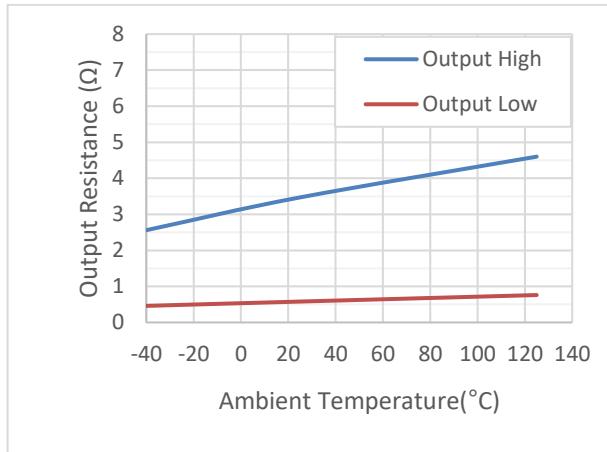


Figure 5.6 Output Resistance vs Temperature

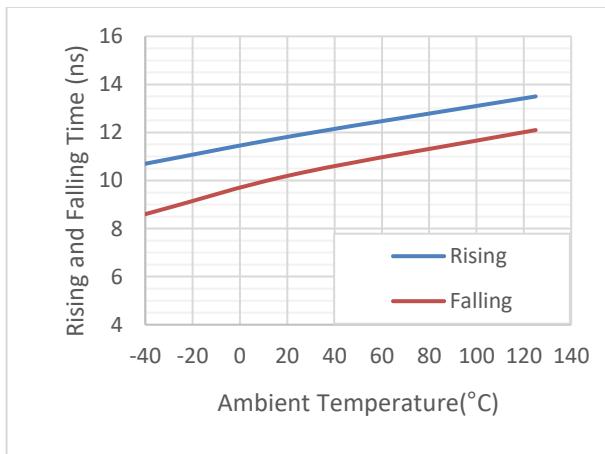


Figure 5.7 Typical Rise Time &amp; Fall Time vs Temperature

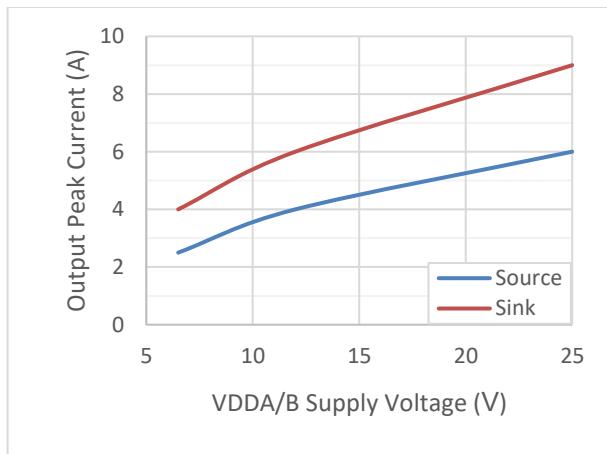


Figure 5.8 Output Peak Current vs VDDA/B Supply Voltage

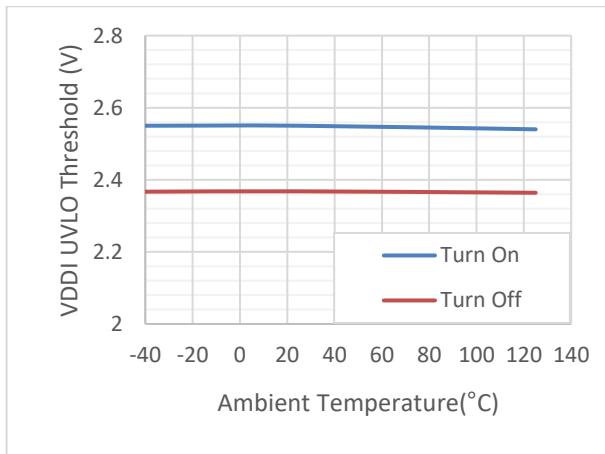


Figure 5.9 VDDI UVLO Threshold vs Temperature

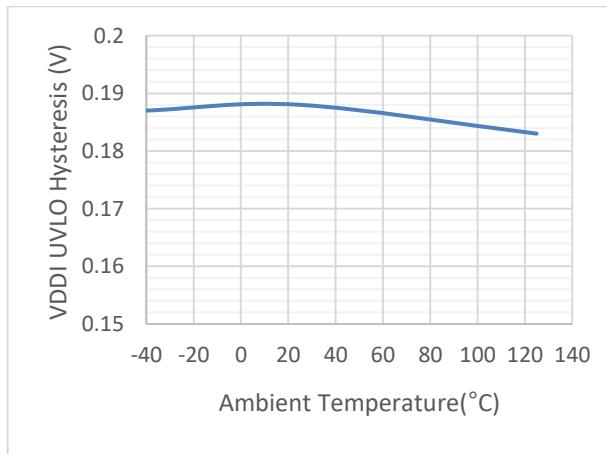


Figure 5.10 VDDI UVLO Hysteresis vs Temperature

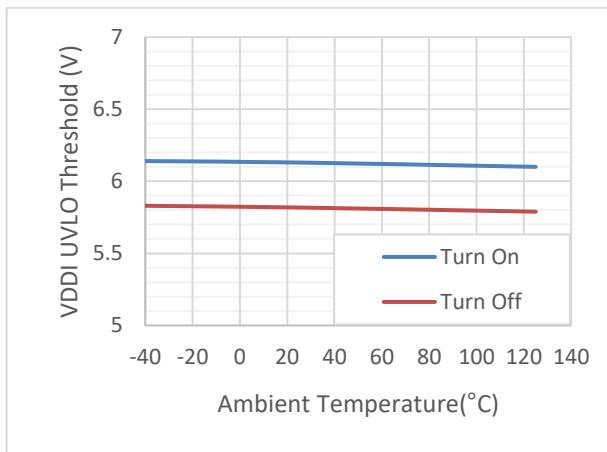


Figure 5.11 6V VDDA/B UVLO Threshold vs Temperature

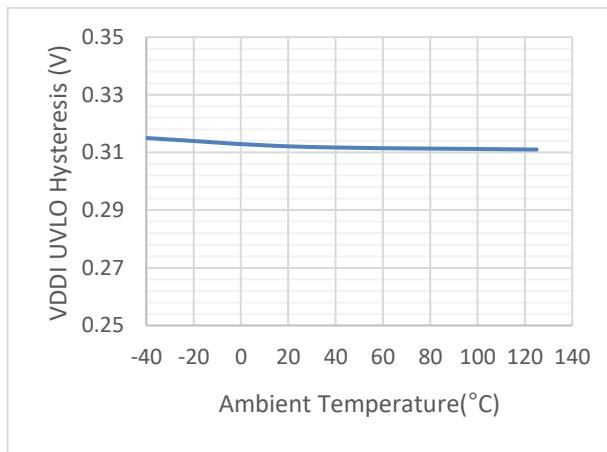


Figure 5.12 6V VDDA/B UVLO Hysteresis vs Temperature

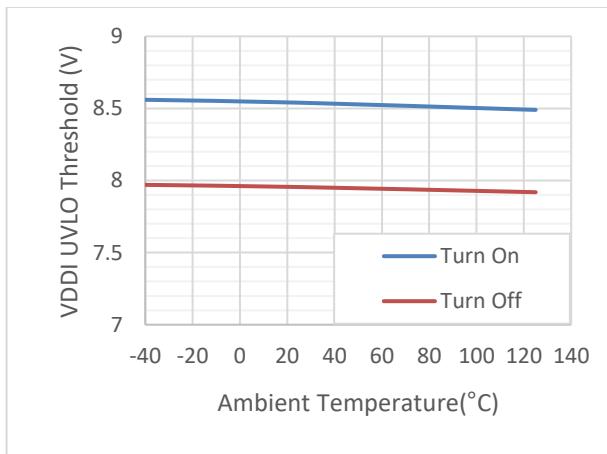


Figure 5.13 8V VDDA/B UVLO Threshold vs Temperature

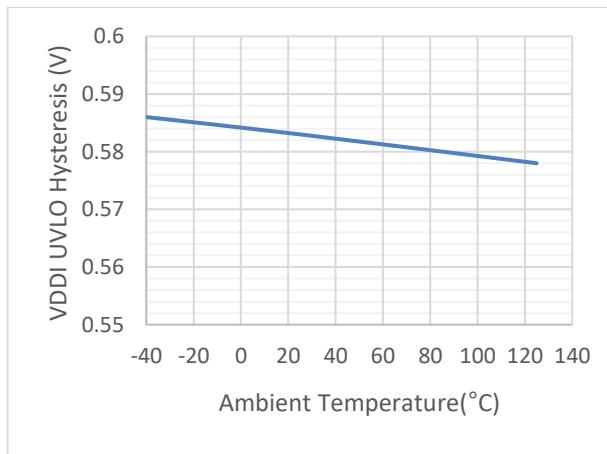


Figure 5.14 8V VDDA/B UVLO Hysteresis vs Temperature

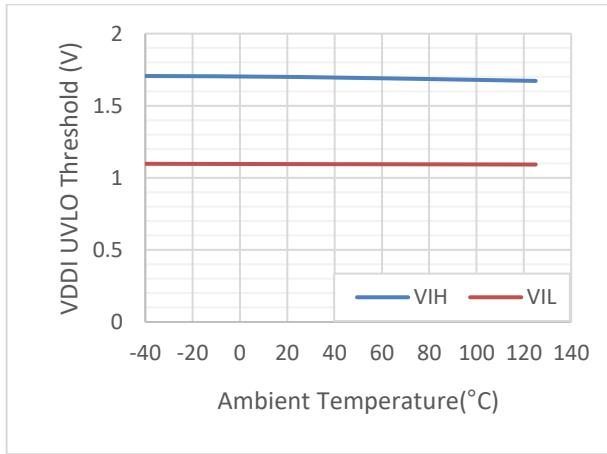


Figure 5.15 INA/INB/DIS Threshold vs Temperature

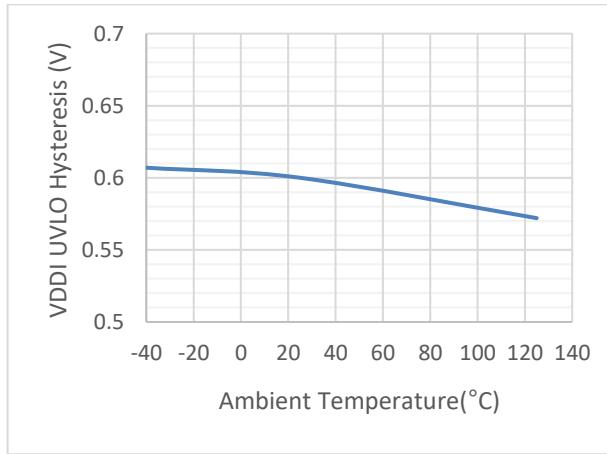


Figure 5.16 INA/INB/DIS Hysteresis vs Temperature

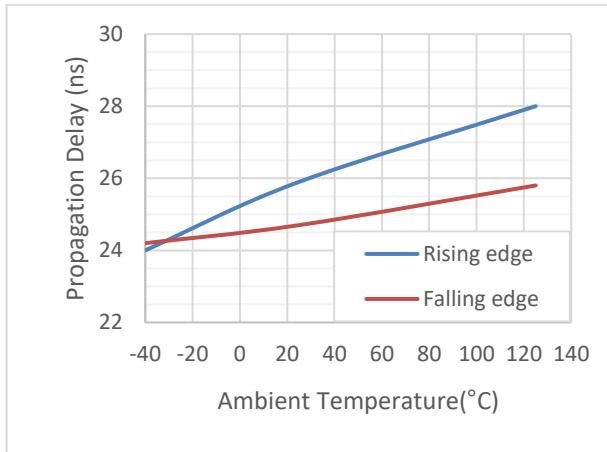


Figure 5.17 Propagation Delay vs Temperature

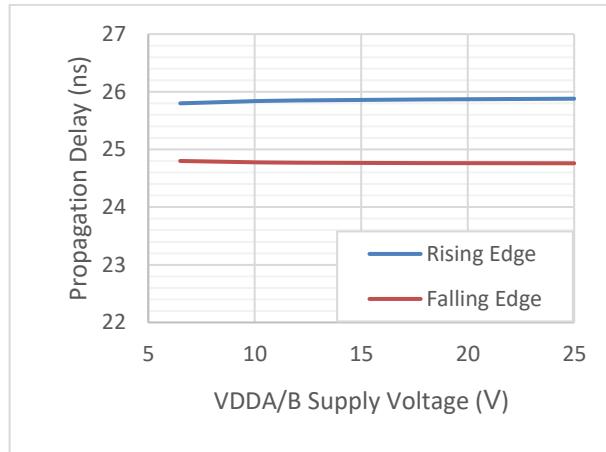


Figure 5.18 Propagation Delay vs VDDA/B

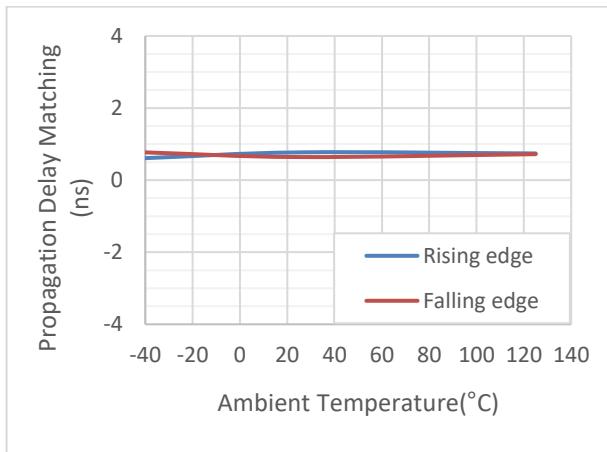


Figure 5.19 Propagation Delay Matching vs Temperature

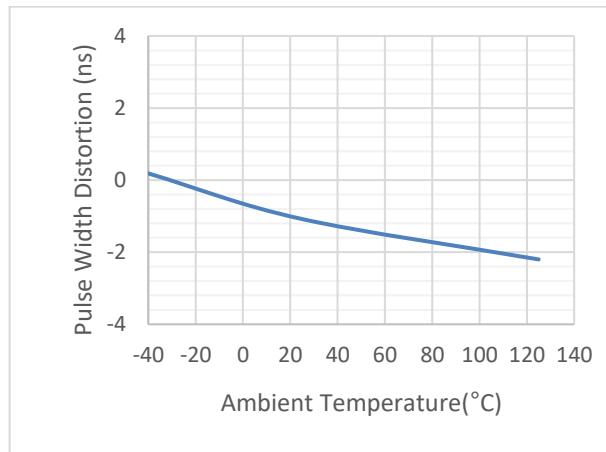


Figure 5.20 Pulse Width Distortion vs Temperature

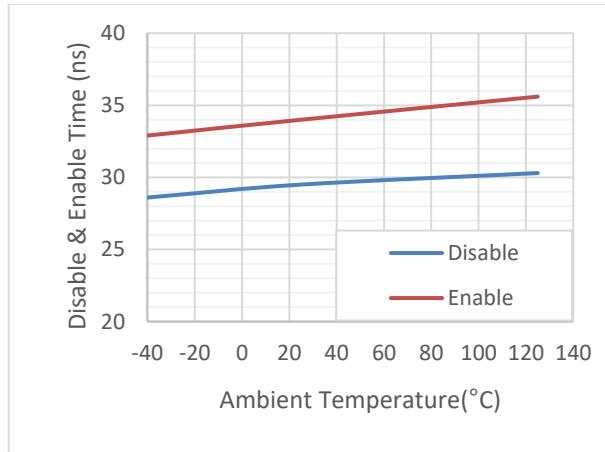


Figure 5.21 Disable &amp; Enable Time vs Temperature

#### 5.4. Parameter Measurement Information

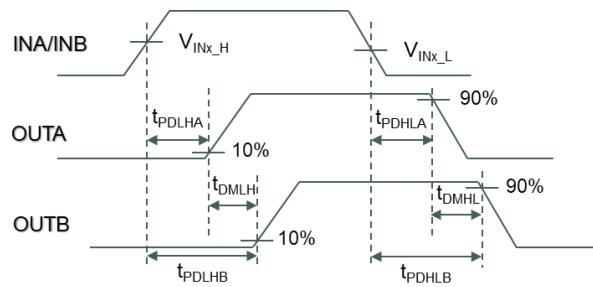


Figure 5.23 Propagation Delay and Channel to Channel Delay Match Time

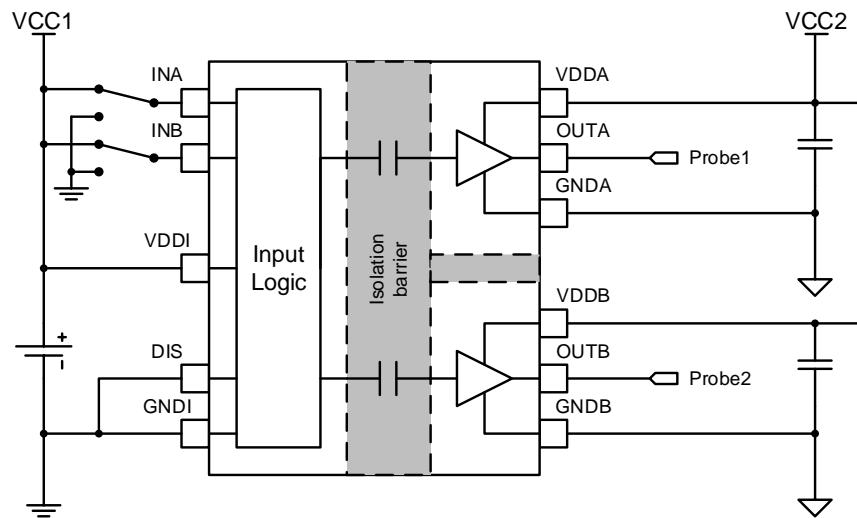


Figure 5.24 Channel to Channel Delay Match Test Circuit

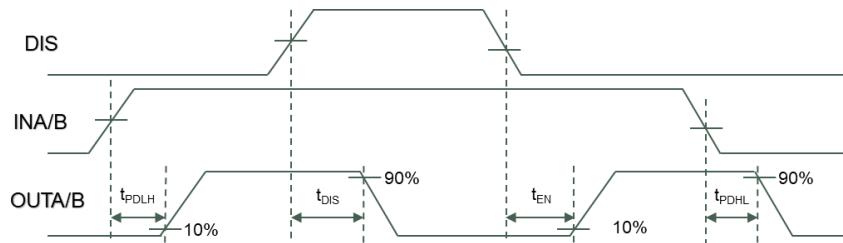


Figure 5.25 Disable Time and Enable Time

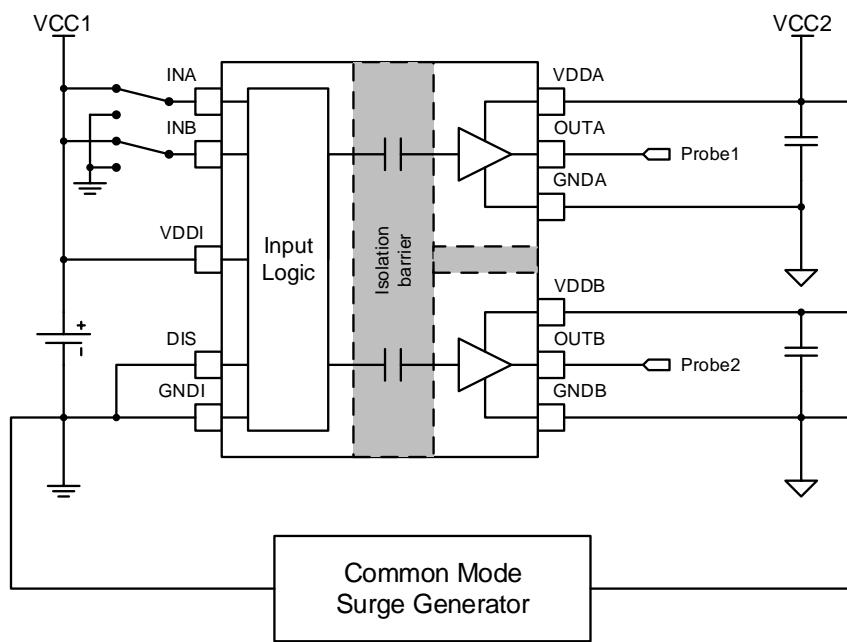


Figure 5.27 Common-Mode Transient Immunity Test Circuit

## 6. High Voltage Feature Description

### 6.1. Insulation Characteristics

Description	Test Condition	Symbol	Value		Unit
			LGA 13	SOW16/14	SOP16
Min. External Air Gap (Clearance)		CLR	3.5	8	4 mm
Min. External Tracking (Creepage)		CPG	3.5	8	4 mm
Distance through the Insulation		DTI		32	um
Comparative Tracking Index	DIN EN 60112 (VDE 0303-11)	CTI		>600	V
Material Group	IEC 60664-1			I	
Installation Classification per DIN VDE 0110					
For Rated Mains Voltage $\leq$ 150Vrms			I to III	I to IV	I to IV
For Rated Mains Voltage $\leq$ 300Vrms			I to II	I to IV	I to III
For Rated Mains Voltage $\leq$ 600Vrms			I	I to IV	I to II
For Rated Mains Voltage $\leq$ 1000Vrms			/	I to III	/
Insulation Specification per DIN VDE V 0884-11:2017-01 <sup>1)</sup>					
Climatic Category			40/125/21		
Pollution Degree	per DIN VDE 0110, Table 1		2		
Maximum Working Isolation Voltage	AC voltage	V <sub>IOWM</sub>	560	1000	700 V <sub>RMS</sub>
	DC voltage		792	1414	990 V <sub>DC</sub>
Maximum Repetitive Isolation Voltage		V <sub>IORM</sub>	792	1414	990 V <sub>peak</sub>
Input to Output Test Voltage, Method B1	V <sub>ini. b</sub> = V <sub>IOTM</sub> , V <sub>pd(m)</sub> = V <sub>IORM</sub> $\times$ 1.5, t <sub>ini</sub> = t <sub>m</sub> = 1 sec, q <sub>pd</sub> $\leq$ 5 pC, 100% production test	V <sub>pd (m)</sub>	1188	/	1485 V <sub>peak</sub>
	V <sub>ini. b</sub> = V <sub>IOTM</sub> , V <sub>pd(m)</sub> = V <sub>IORM</sub> $\times$ 1.875, t <sub>ini</sub> = t <sub>m</sub> = 1 sec, q <sub>pd</sub> $\leq$ 5 pC, 100% production test	V <sub>pd (m)</sub>	/	2652	/ V <sub>peak</sub>
Input to Output Test Voltage, Method A. After Environmental Tests Subgroup 1	V <sub>ini. a</sub> = V <sub>IOTM</sub> , V <sub>pd(m)</sub> = V <sub>IORM</sub> $\times$ 1.3, t <sub>ini</sub> = 60 sec, t <sub>m</sub> = 10 sec, q <sub>pd</sub> $\leq$ 5 pC	V <sub>pd (m)</sub>	1030	/	1287 V <sub>peak</sub>
	V <sub>ini. a</sub> = V <sub>IOTM</sub> , V <sub>pd(m)</sub> = V <sub>IORM</sub> $\times$ 1.6, t <sub>ini</sub> = 60 sec, t <sub>m</sub> = 10 sec, q <sub>pd</sub> $\leq$ 5 pC	V <sub>pd (m)</sub>	/	2263	/ V <sub>peak</sub>
Input to Output Test Voltage, Method A. After Input and Output Safety Test Subgroup 2 and Subgroup 3	V <sub>ini. a</sub> = V <sub>IOTM</sub> , V <sub>pd(m)</sub> = V <sub>IORM</sub> $\times$ 1.2, t <sub>ini</sub> = 60 sec, t <sub>m</sub> = 10 sec, q <sub>pd</sub> $\leq$ 5 pC	V <sub>pd (m)</sub>	950	1697	1188 V <sub>peak</sub>

<b>Description</b>		<b>Test Condition</b>	<b>Symbol</b>	<b>Value</b>		<b>Unit</b>
Maximum Transient Isolation Voltage	t = 60 sec	V <sub>IOTM</sub>	3535	8000	4242	V <sub>peak</sub>
Maximum Surge Isolation Voltage	Test method per IEC62368-1, 1.2/50us waveform, V <sub>TEST</sub> = 1.3 × V <sub>IOSM</sub>	V <sub>IOSM</sub>	3500	/	6000	V <sub>peak</sub>
	Test method per IEC62368-1, 1.2/50us waveform, V <sub>TEST</sub> = 1.6 × V <sub>IOSM</sub>		/	6250	/	V <sub>peak</sub>
Isolation Resistance	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = T <sub>S</sub>	R <sub>IO</sub>	>10 <sup>9</sup>			Ω
	V <sub>IO</sub> = 500 V, 100 °C ≤ T <sub>amb</sub> ≤ 125 °C		>10 <sup>11</sup>			Ω
Isolation Capacitance	f = 1MHz	C <sub>IO</sub>	1.2			pF
Insulation Specification per UL1577						
Withstand Isolation Voltage	V <sub>TEST</sub> = 1.2 × V <sub>ISO</sub> , t = 1 sec, 100% production test	V <sub>ISO</sub>	2500	5700	3000	V <sub>rms</sub>

- 1) This coupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

## 6.2. Safety-Limiting Values

Reinforced isolation safety-limiting values as outlined in VDE-0884-11 of NSI6622x-xSWxR (SOW16/SOW14)

<b>Description</b>		<b>Test Condition</b>	<b>Side</b>	<b>Value</b>	<b>Unit</b>	
Safety Supply Power	R <sub>θJA</sub> = 97 °C/W <sup>1)</sup> , T <sub>J</sub> = 150 °C, T <sub>A</sub> = 25 °C		Input	12	mW	
			Driver A, Driver B	638	mW	
			Total	1288	mW	
Safety Supply Current	R <sub>θJA</sub> = 97 °C/ W <sup>1)</sup> , VDDA/B = 12V, T <sub>J</sub> = 150 °C, T <sub>A</sub> = 25 °C		Driver A, Driver B	53.1	mA	
	R <sub>θJA</sub> = 97 °C/ W <sup>1)</sup> , VDDA/B = 25V, T <sub>J</sub> = 150 °C, T <sub>A</sub> = 25 °C		Driver A, Driver B	25.5	mA	
Safety Temperature <sup>2)</sup>				150	°C	

- 1) Calculate with the junction-to-air thermal resistance, R<sub>θJA</sub>, of SOW16/SOW14 package ([Thermal Information Table](#)) which is that of a device installed on a low effective thermal conductivity test board (1s) according to JESD51-3.  
 2) The maximum safety temperature has the same value as the maximum junction temperature (T<sub>J</sub>) specified for the device.

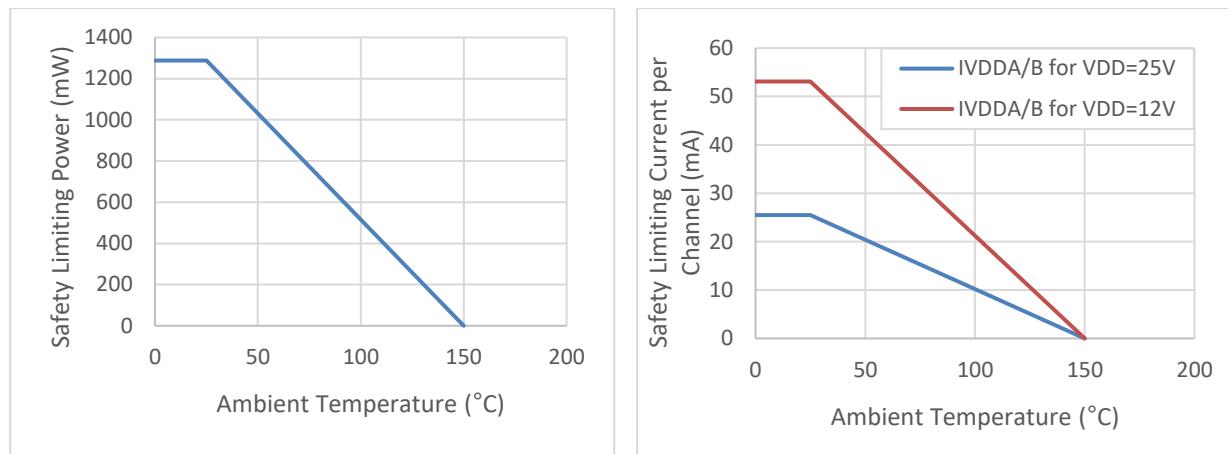


Figure 6.1 NSI6622x-DSWR Thermal Derating Curve, Dependence of Safety Limiting Values with Case Temperature per DIN VDE V 0884-11

Basic isolation safety-limiting values as outlined in VDE-0884-11 of NSI6602x-xSPNR (SOP16)

Description	Test Condition	Side	Value	Unit
Safety Supply Power	$R_{\theta JA} = 150.5 \text{ }^{\circ}\text{C}/\text{W}^1$ , $T_J = 150 \text{ }^{\circ}\text{C}$ , $T_A = 25 \text{ }^{\circ}\text{C}$	Input	12	mW
		Driver A, Driver B	409	mW
		Total	830	mW
Safety Supply Current	$R_{\theta JA} = 150.5 \text{ }^{\circ}\text{C}/\text{W}^1$ , $VDDA/B = 12\text{V}$ , $T_J = 150 \text{ }^{\circ}\text{C}$ , $T_A = 25 \text{ }^{\circ}\text{C}$	Driver A, Driver B	34.0	mA
	$R_{\theta JA} = 150.5 \text{ }^{\circ}\text{C}/\text{W}^1$ , $VDDA/B = 25\text{V}$ , $T_J = 150 \text{ }^{\circ}\text{C}$ , $T_A = 25 \text{ }^{\circ}\text{C}$	Driver A, Driver B	16.3	mA
Safety Temperature <sup>2)</sup>			150	°C

- 1) Calculate with the junction-to-air thermal resistance,  $R_{\theta JA}$ , of SOP16 package ([Thermal Information Table](#)) which is that of a device installed on a low effective thermal conductivity test board (1s) according to JESD51-3.
- 2) The maximum safety temperature has the same value as the maximum junction temperature ( $T_J$ ) specified for the device.

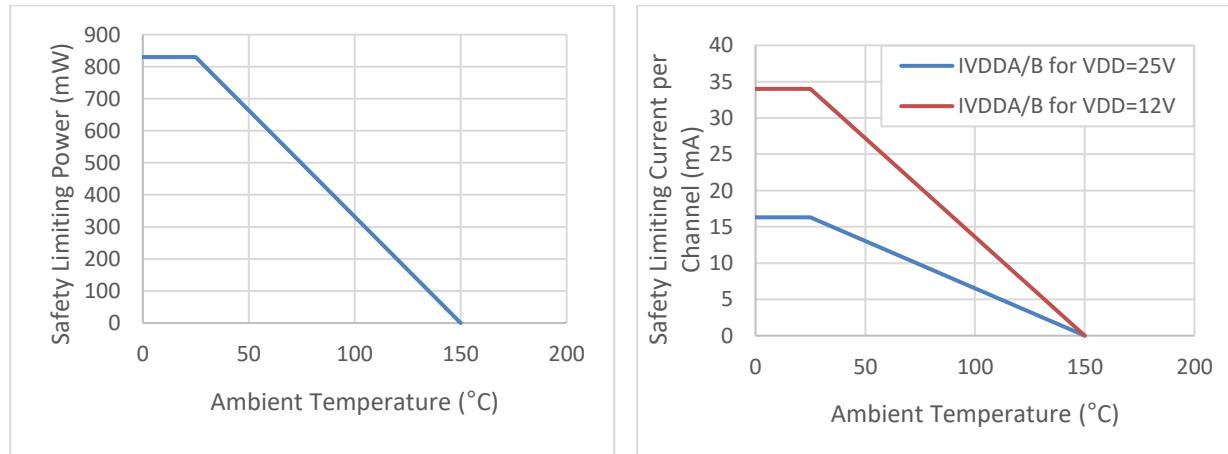


Figure 6.2 NSI6622x-DSWR Thermal Derating Curve, Dependence of Safety Limiting Values with Case Temperature per DIN VDE V 0884-11

Basic isolation safety-limiting values as outlined in VDE-0884-11 of NSI6622x-xLAR (LGA13)

<i>Description</i>		<i>Test Condition</i>	<i>Side</i>	<i>Value</i>	<i>Unit</i>
Safety Supply Power	$R_{\theta JA} = 209.5 \text{ }^{\circ}\text{C}/\text{W}^1), T_J = 150 \text{ }^{\circ}\text{C}, T_A = 25 \text{ }^{\circ}\text{C}$		Input	12	mW
			Driver A, Driver B	293	mW
			Total	598	mW
Safety Supply Current	$R_{\theta JA} = 209.5 \text{ }^{\circ}\text{C}/\text{W}^1), VDDA/B = 12V, T_J = 150 \text{ }^{\circ}\text{C}, T_A = 25 \text{ }^{\circ}\text{C}$		Driver A, Driver B	24.4	mA
			Driver A, Driver B	11.7	mA
Safety Temperature <sup>2)</sup>				150	°C

- 1) Calculate with the junction-to-air thermal resistance,  $R_{\theta JA}$ , of LGA13 package ([Thermal Information Table](#)) which is that of a device installed on a low effective thermal conductivity test board (1s) according to JESD51-3.
- 2) The maximum safety temperature has the same value as the maximum junction temperature ( $T_J$ ) specified for the device.

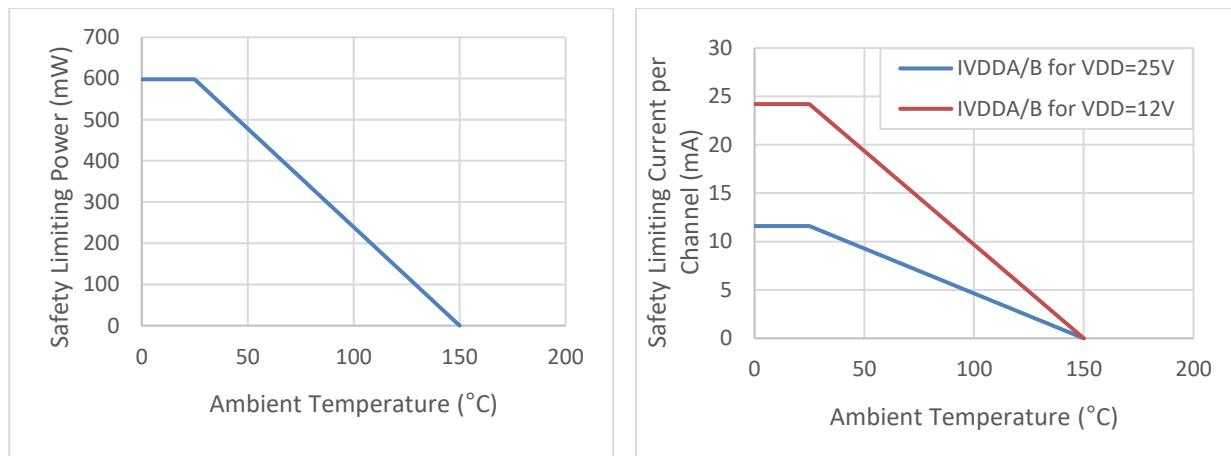


Figure 6.3 NSI6622x-DLAR Thermal Derating Curve, Dependence of Safety Limiting Values with Case Temperature per DIN VDE V 0884-11

### 6.3. Safety-Related Certifications

The NSI6622x-DSWxR(SOW16/SOW14) are approved or pending approval by the organizations listed in table.

<i>CUL</i>		<i>VDE</i>	<i>CQC</i>
UL 1577 Component Recognition Program	Approved under CSA Component Acceptance Notice 5A	DIN VDE V 0884-11: 2017-01	Certified by CQC11-471543-2012 GB4943.1-2011
Single Protection, 5700Vrms Isolation voltage	Single Protection, 5700Vrms Isolation voltage	Reinforced insulation at $V_{IORM}=1414V_{PEAK}$ $V_{IOSM}=6250V_{PEAK}$ $V_{IOTM}=8000V_{PEAK}$	Reinforced insulation
E500602	E500602	Certification No. 40052820	CQC20001264939

The NSI6622x-DSPNR(SOP16) are approved or pending approval by the organizations listed in table.

CUL		VDE	CQC
UL 1577 Component Recognition Program	Approved under CSA Component Acceptance Notice 5A	DIN VDE V 0884-11(VDE V 0884-11):2017-01	Certified by CQC11-471543-2012 GB4943.1-2011
Single Protection, 3000Vrms Isolation voltage	Single Protection, 3000Vrms Isolation voltage	Basic insulation at $V_{IORM}=990V_{PEAK}$ $V_{IOSM}=6000V_{PEAK}$ $V_{IOTM}=4242V_{PEAK}$	Basic insulation
E500602	E500602	File (pending)	CQC21001289931

The NSi6622x-DLAR(LGA13) are approved or pending approval by the organizations listed in table.

CUL		VDE	CQC
UL1577 Component Recognition Program	Approved under CSA Component Acceptance Notice 5A	DIN VDE V 0884-11: 2017-01	Certified by CQC11-471543-2012 GB4943.1-2011
Single Protection, 2500Vrms Isolation voltage	Single Protection,2500Vrms Isolation voltage	Basic Insulation at $V_{IORM}=792V_{PEAK}$ $V_{IOSM}=3500V_{PEAK}$ $V_{IOTM}=3535V_{PEAK}$	Basic insulation
E500602	E500602	File (pending)	CQC21001289933

## 7. Function Description

### 7.1. Overview

NSi6622 is a high reliability dual channel isolated gate driver which could be designed in variety switching power and motor drive topologies. NSi6622 has some useful protections, such as under voltage lock-out (UVLO) for both input and output supply, a disable pin, default low output as input is floating. The functional circuit block diagram is shown as below:

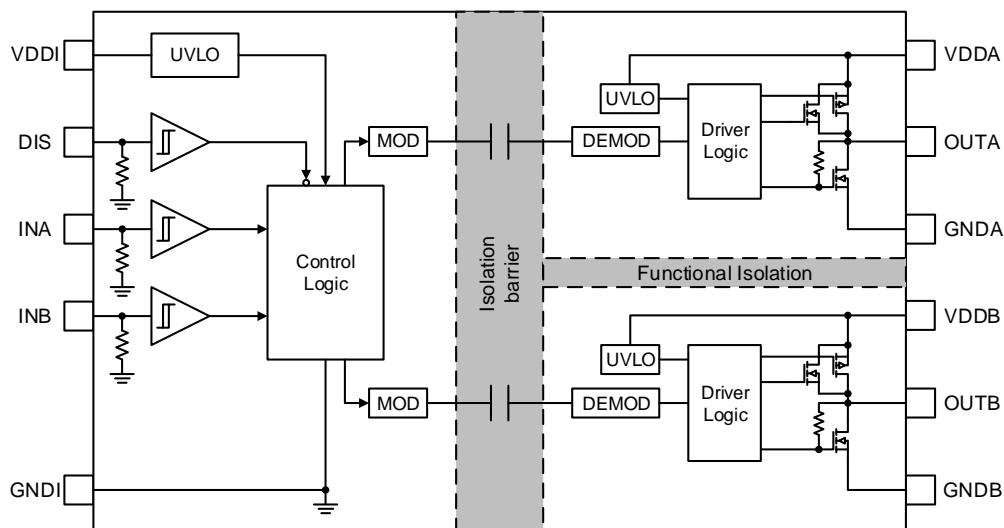


Figure 7.1 Functional Block Diagram

## 7.2. Under Voltage Lock Out (UVLO)

The NSi6622 has an internal under voltage lock out (UVLO) protection on both input and output supply circuit blocks. The driver output is held low by an active clamp circuit when the supply voltage of VDDI or VDDA/VDDB is lower than  $V_{VDD\_ON}$  at power-up status or lower than  $V_{VDD\_OFF}$  after power-up, regardless of the status of the input pins.

The VDDI and VDDA/B ULVO protections have hysteresis ( $V_{VDD\_HYS}$ ) to prevent chatter noise from VDD supply and allow small drops in supply power which are usually happened in startup.

### 7.3. Input and Output Logic Table

When the device is power up, setting the DIS pin high can shut down both outputs simultaneously. Left open or grounding the DIS pin can allow the device operating normally.

Table 7.1 Output status vs. Input and Power status

<i>VDDI</i> <i>status</i>	<i>VDDA/B</i> <i>status</i>	<i>DIS</i>	<i>IN</i>		<i>OUT</i>		<i>NOTE<sup>1)</sup></i>
			<i>A</i>	<i>B</i>	<i>A</i>	<i>B</i>	
PU	PU	L or O	L	H	L	H	
PU	PU	L or O	H	L	H	L	
PU	PU	L or O	H	H	H	H	
PU	PU	L or O	L	L	L	L	
PU	PU	L or O	O	O	L	L	
PU	PU	H	X	X	L	L	
PU	PD	X	X	X	L	L	
PD	PU	X	X	X	L	L	

1) PD= Power Down; PU= Power Up; H= Logic High; L= Logic Low; O= Left Open; X= Irrelevant.

### 7.4. ESD Protection

Figure 7.3 shows the multiple diodes involved in the ESD protection part of NSI6622.

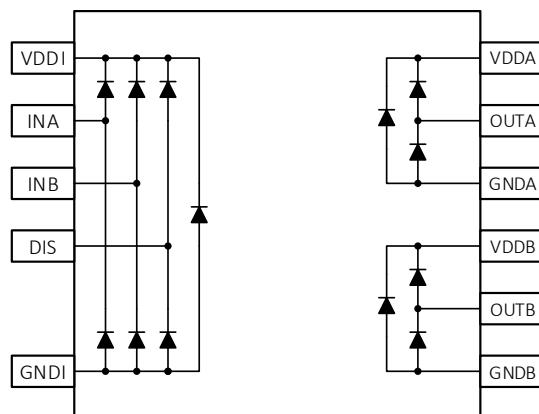


Figure 7.2 ESD Structure

## 8. Application Note

### 8.1. Typical Application Circuit

The circuit shows a typical half-bridge configuration by using the driver NSi6622 which could be used in several popular power converter topologies such as half-bridge/full bridge/LLC isolated topologies, buck-boost topologies, and 3-phase motor drive applications.

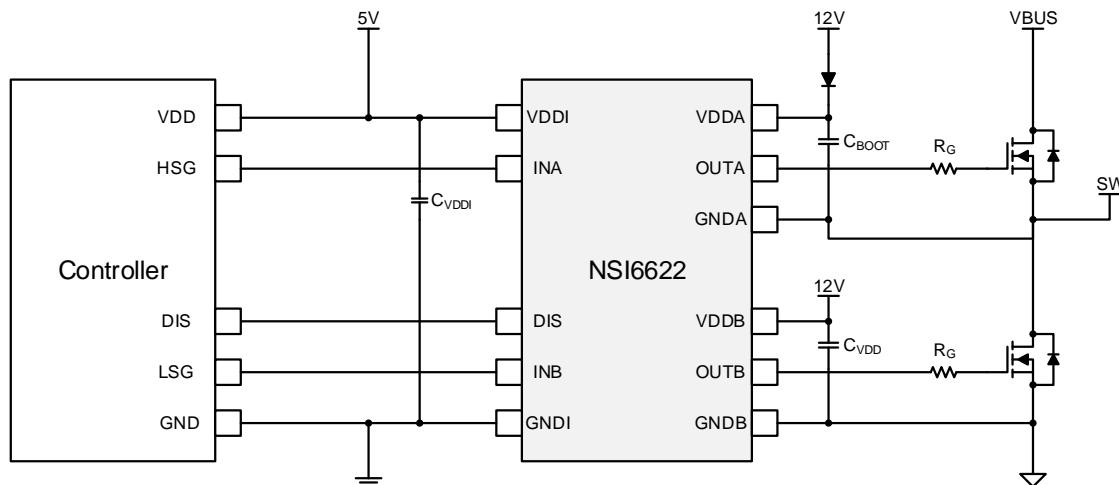


Figure 8.1 Typical Half-Bridge Application Schematic

### 8.2. PCB Layout

PCB layout is important to get optimal performance. Some key guidelines are given as below:

- Low-ESR and low-ESL bypass capacitors should be placed close to the device between pin VDDI to GND and pin VDDA/B to GNDA/B.
- There is high frequency switching current that charges and discharges the gate of external power transistor, leading to EMI and ring issues. The parasitic inductance of this loop should be minimized, by decreasing loop area and placing NSi6622 close to power transistor.
- Large amount of copper should be placed at VDDA/B pin and GNDA/B pin for thermal dissipation.
- To ensure isolation performance between primary and secondary side, the space under the device should keep free from any plane, trace, pad or via.

## 9. Package information

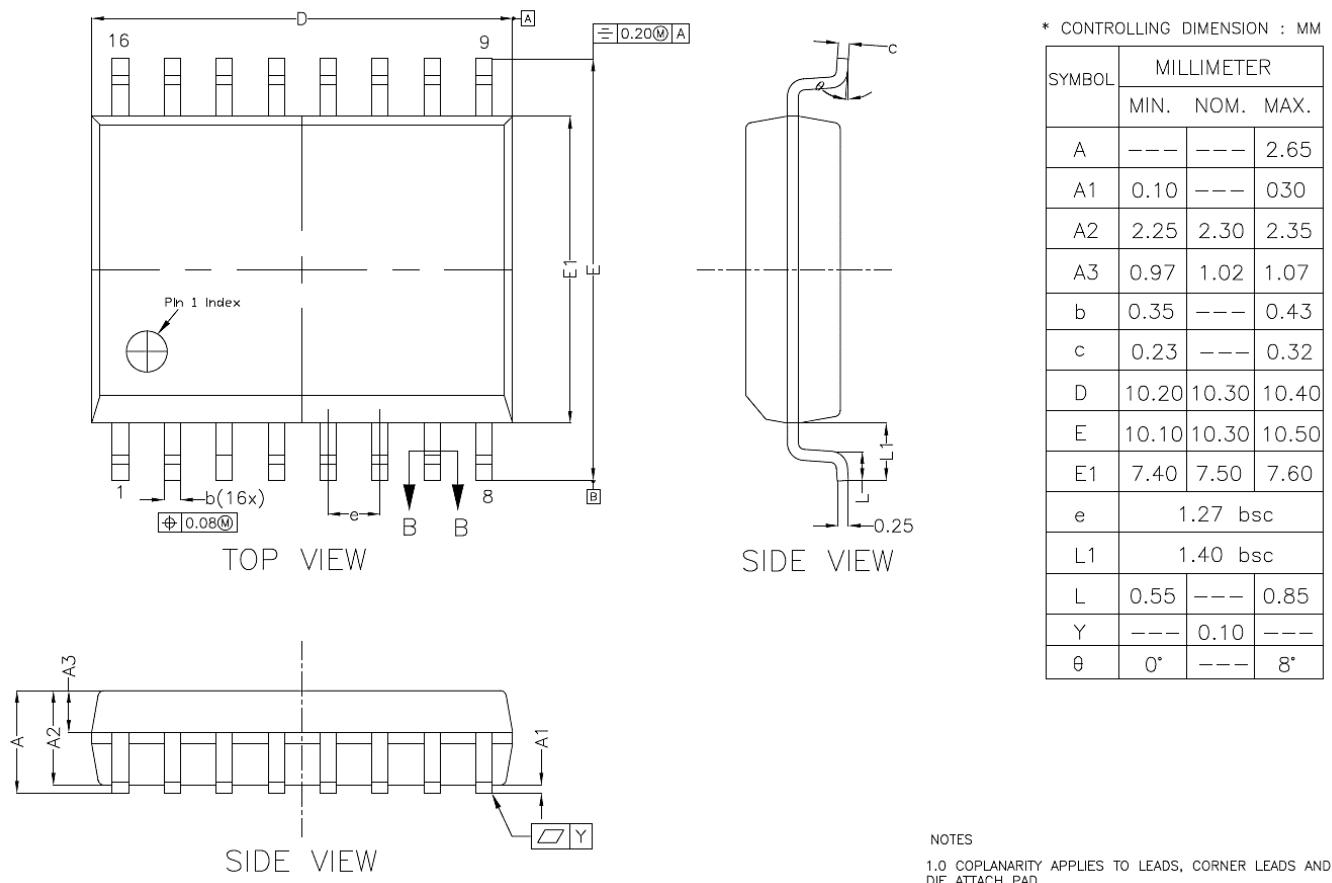


Figure 9.1 SOW16 Package Shape and Dimension

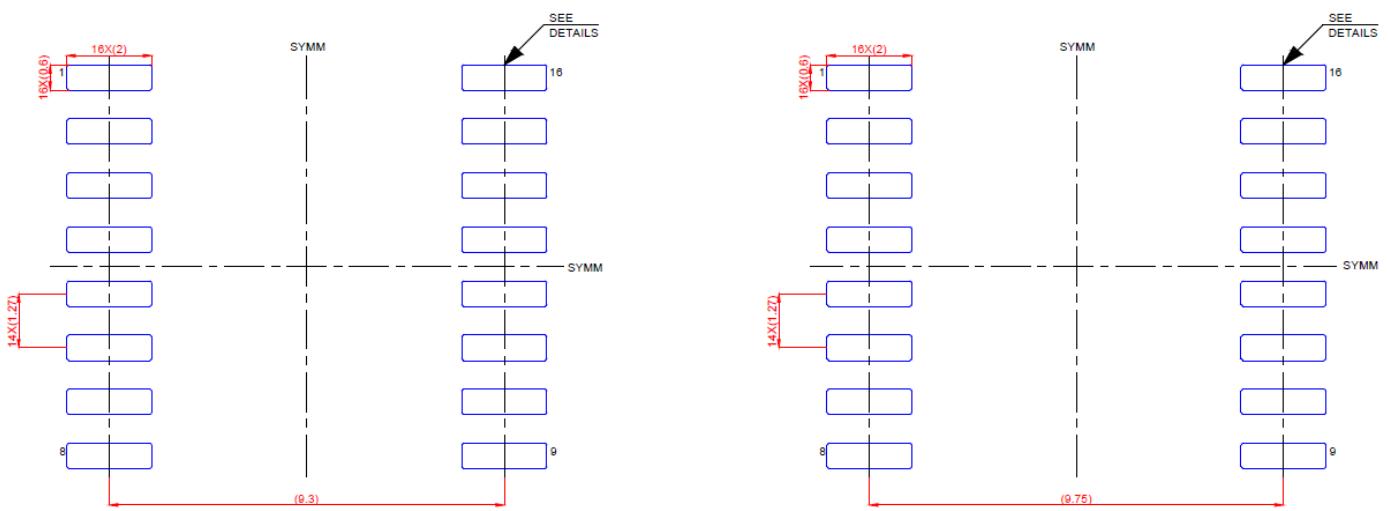


Figure 9.2 SOW16 Package Board Layout Example(mm)

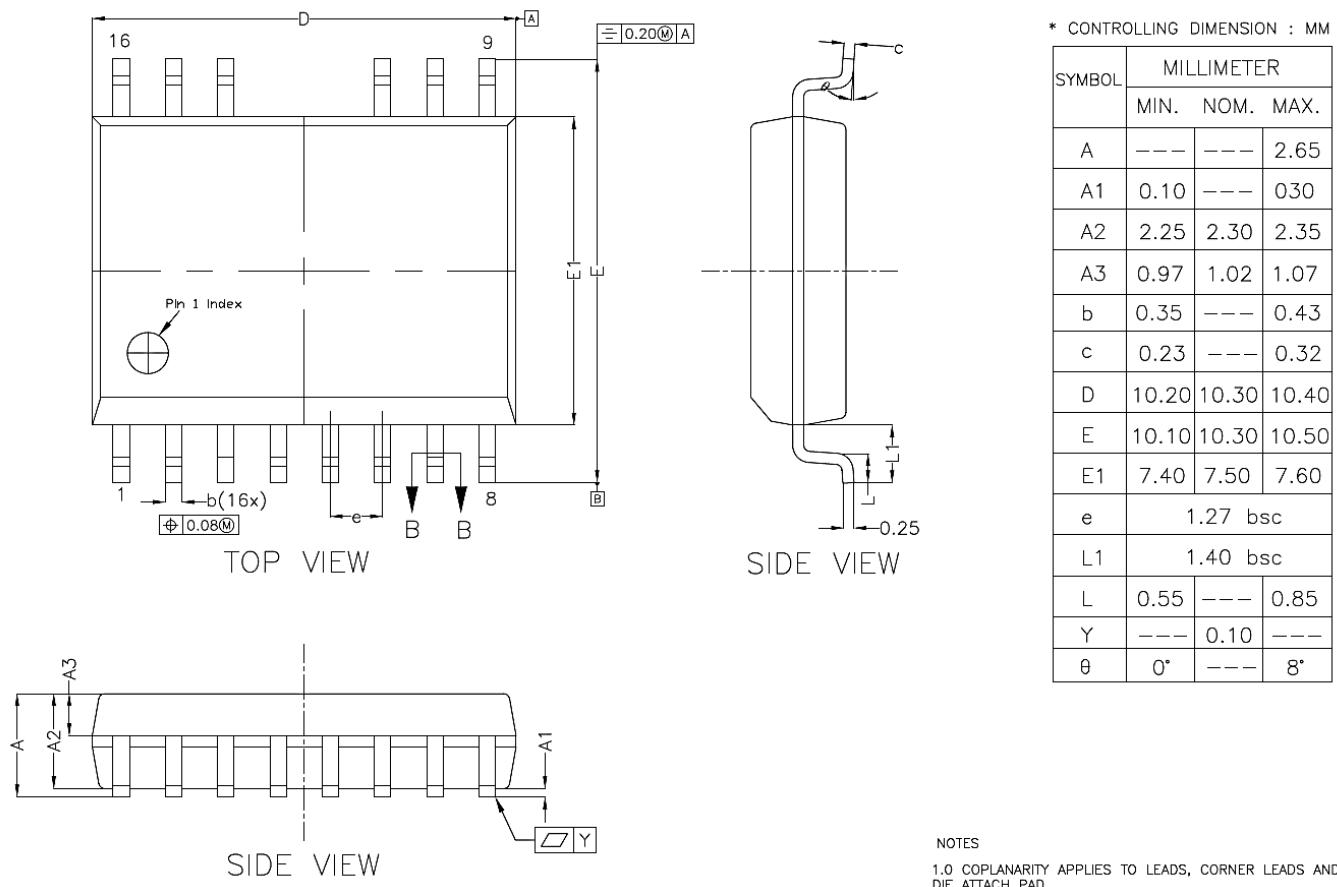


Figure 9.3 SOW14 Package Shape and Dimension

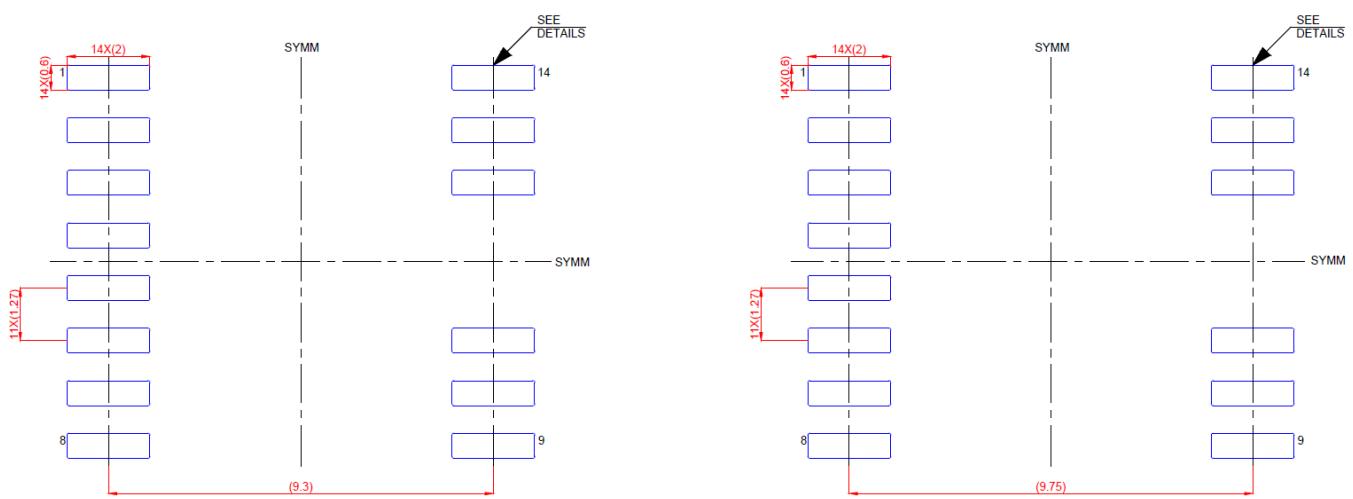


Figure 9.4 SOW14 Package Board Layout Example(mm)

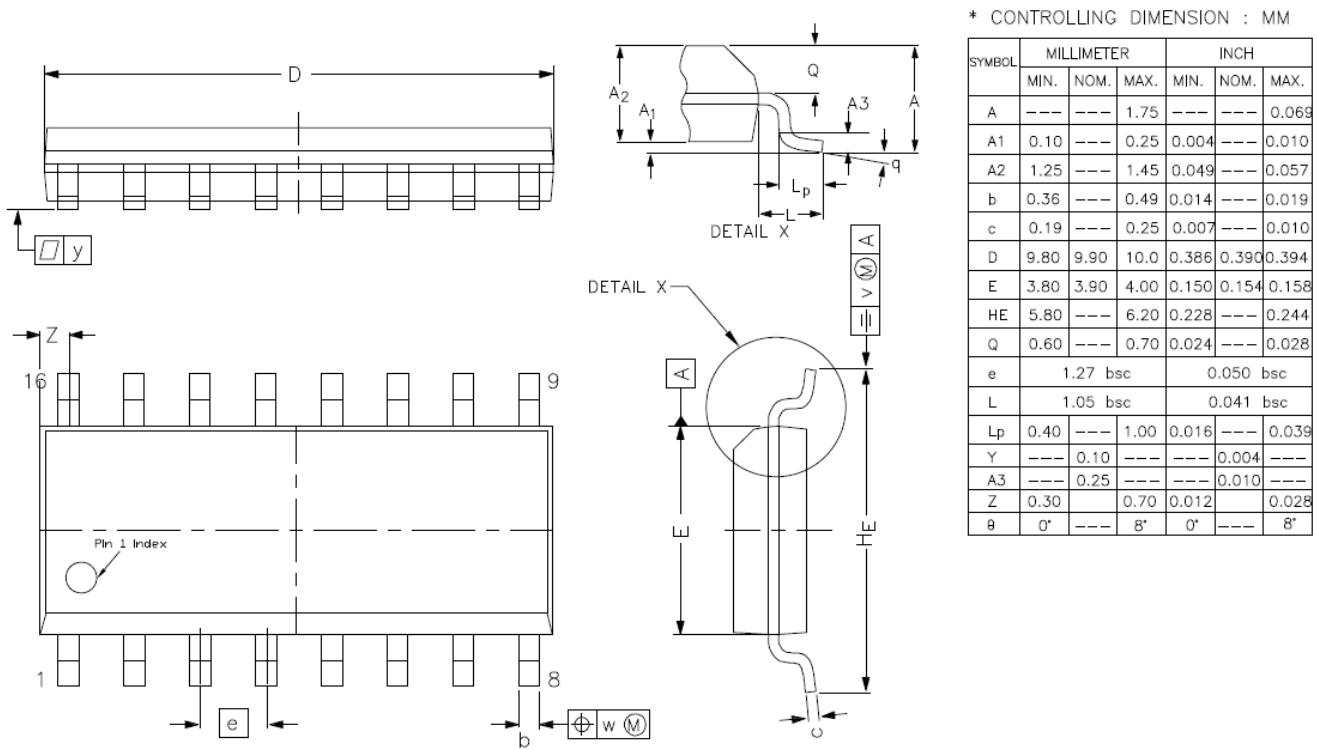


Figure 9.5 SOP16 Package Shape and Dimension

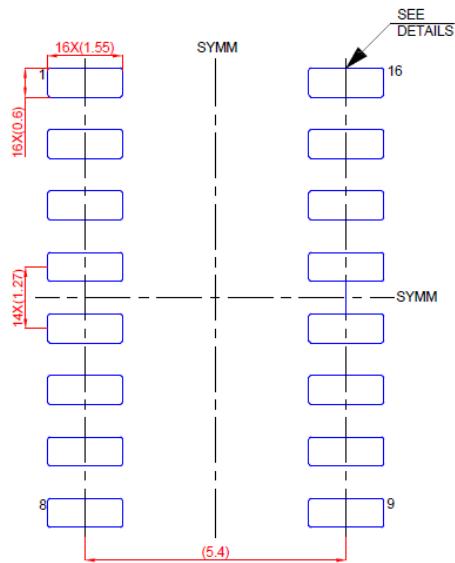


Figure 9.6 SOP16 Package Board Layout Example(mm)

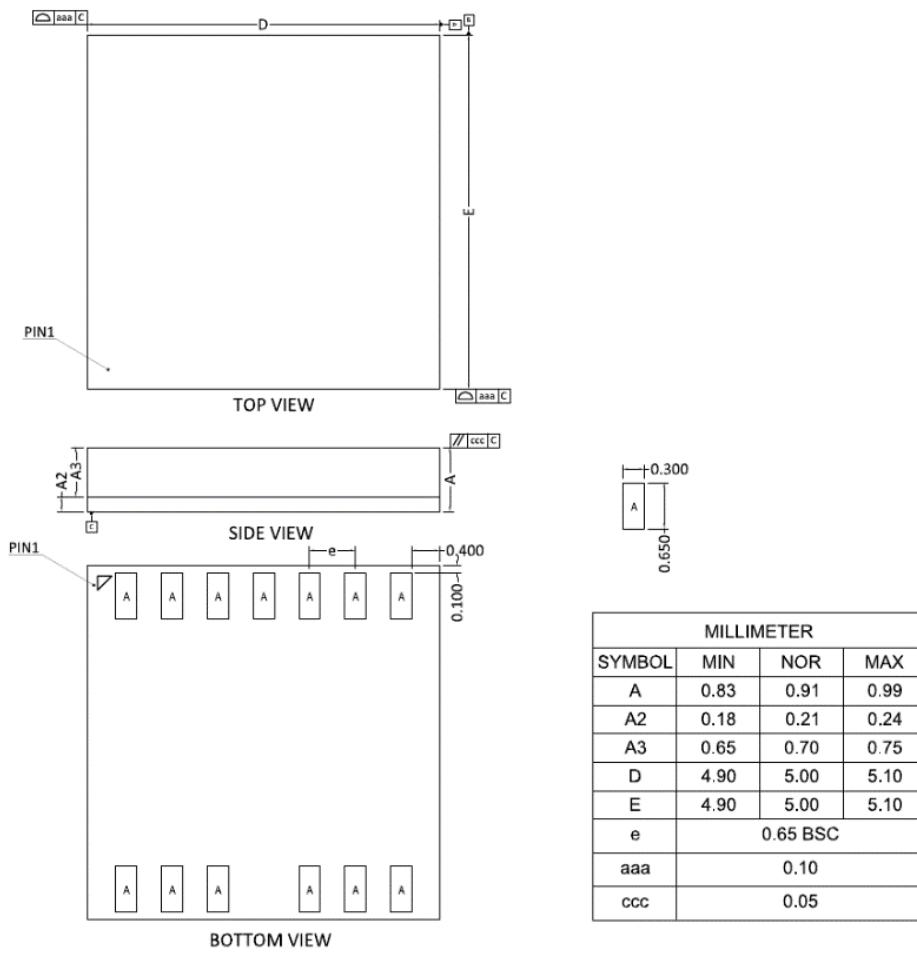


Figure 9.7 LGA13 Package Shape and Dimension

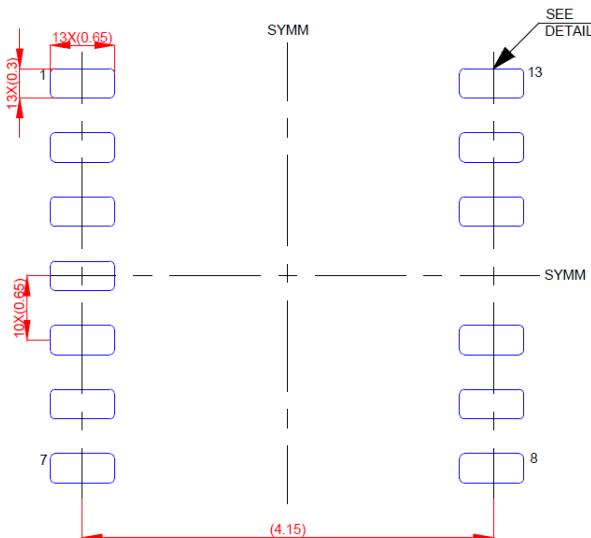


Figure 9.8 LGA13 Package Board Layout Example(mm)

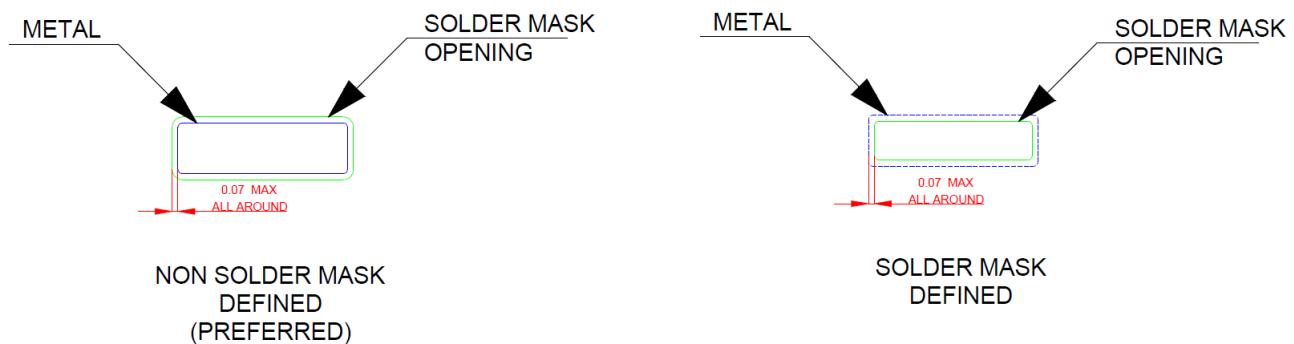
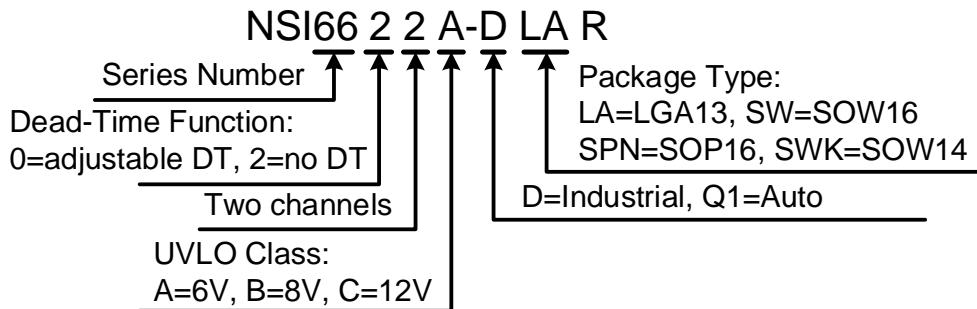


Figure 9.9 Solder Mask Details(mm)

## 10. Ordering Information

Part No.	Isolation Rating( $kV_{RMS}$ )	Driver-side UVLO TYP.	Temperature	Auto-motive	Package Type	Package Drawing	MSL	SPQ
NSI6622A-DSWR	5.7	6V	-40 to 125°C	NO	SOP16(300mil)	SOW16	2	1000
NSI6622A-DSWKR	5.7	6V	-40 to 125°C	NO	SOP14(300mil)	SOW14	2	1000
NSI6622A-DSPNR	3.0	6V	-40 to 125°C	NO	SOP16(150mil)	SOP16	1	2500
NSI6622A-DLAR	2.5	6V	-40 to 125°C	NO	LGA13	LGA13	3	3000
NSI6622B-DSWR	5.7	8V	-40 to 125°C	NO	SOP16(300mil)	SOW16	2	1000
NSI6622B-DSWKR	5.7	8V	-40 to 125°C	NO	SOP14(300mil)	SOW14	2	1000
NSI6622B-DSPNR	3.0	8V	-40 to 125°C	NO	SOP16(150mil)	SOP16	1	2500
NSI6622B-DLAR	2.5	8V	-40 to 125°C	NO	LGA13	LGA13	3	3000
NSI6622C-DSWR	5.7	13V	-40 to 125°C	NO	SOP16(300mil)	SOW16	2	1000
NSI6622C-DSWKR	5.7	13V	-40 to 125°C	NO	SOP14(300mil)	SOW14	2	1000
NSI6622C-DSPNR	3.0	13V	-40 to 125°C	NO	SOP16(150mil)	SOP16	1	2500
NSI6622C-DLAR	2.5	13V	-40 to 125°C	NO	LGA13	LGA13	3	3000

### Part Number Rule:



## 11. Tape and Reel Information

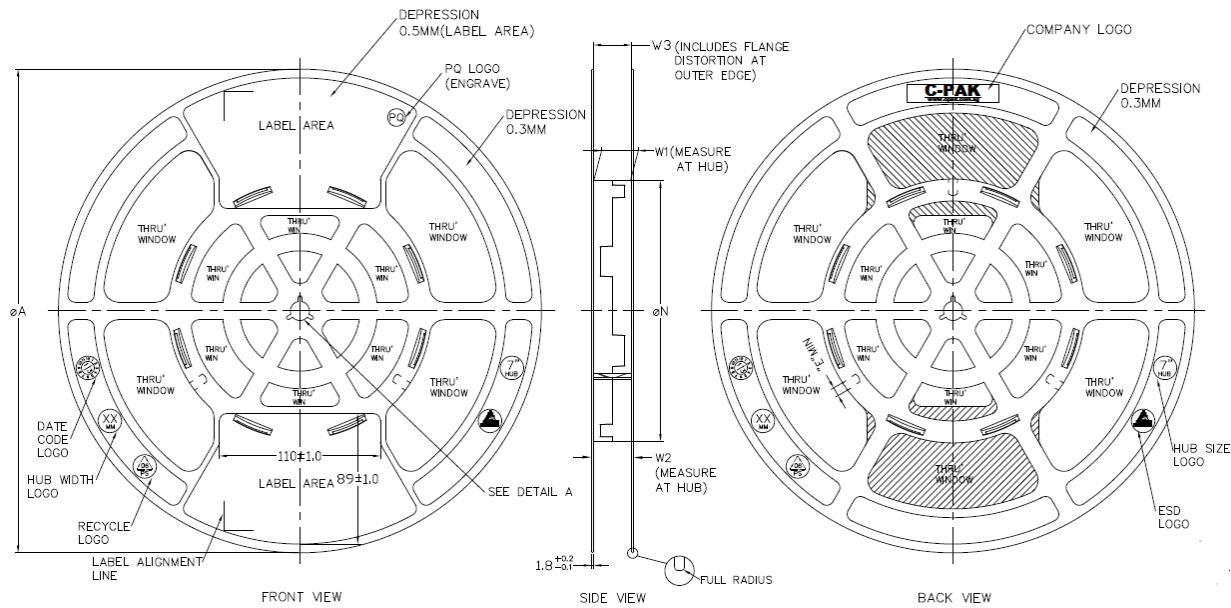


Figure 11.1 Tape Information

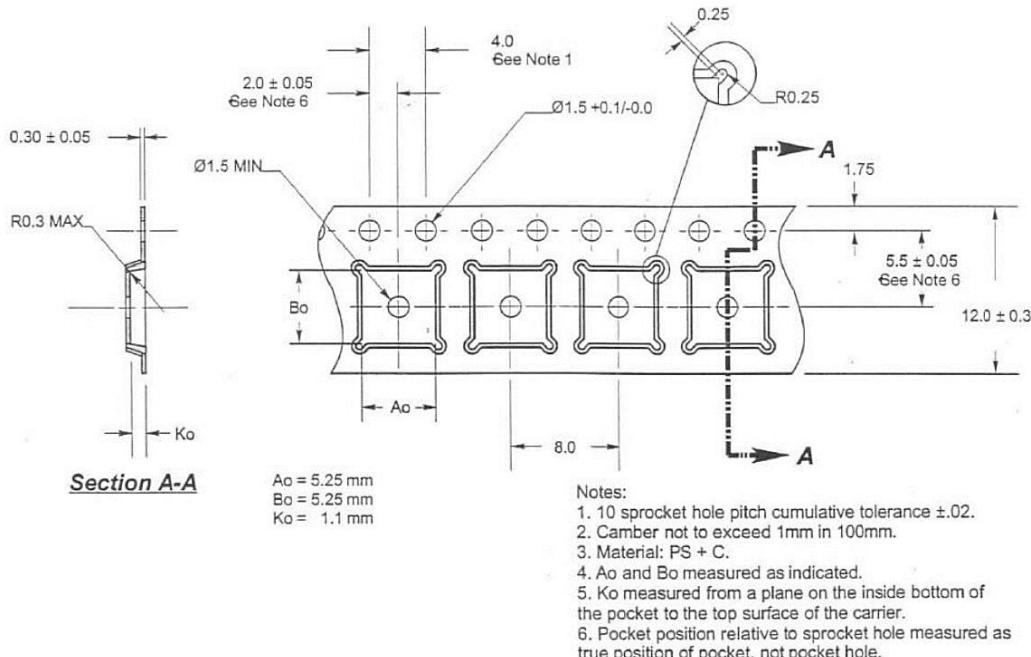
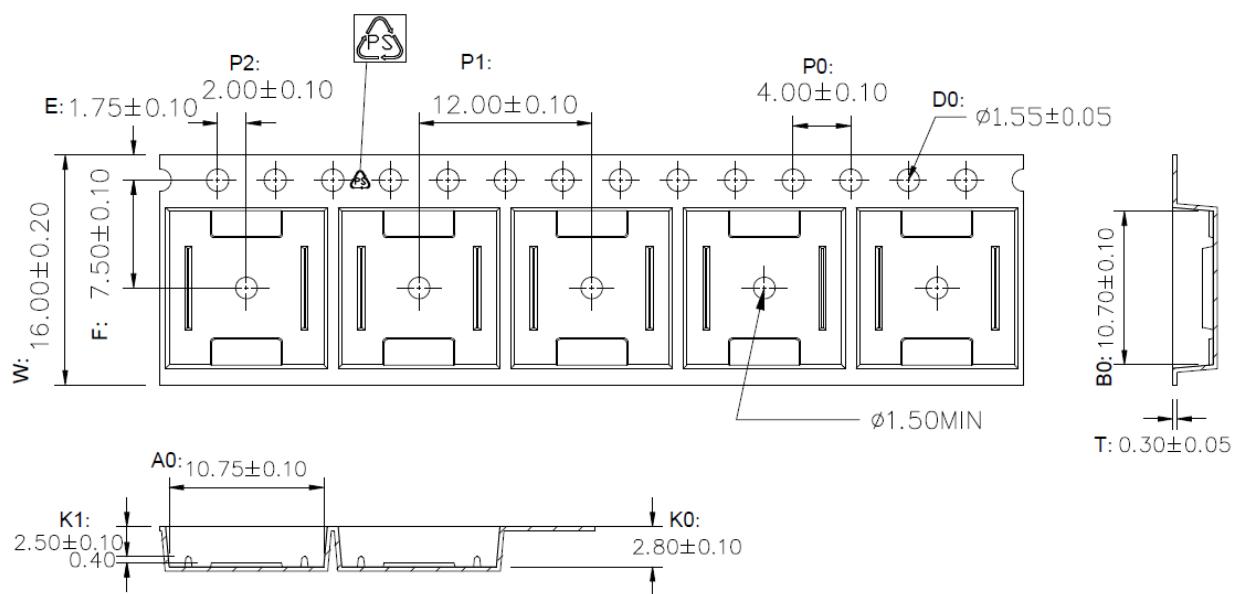


Figure 11.2 LGA13 Reel Information



1. 10 sprocket hole pitch cumulative tolerance  $\pm 0.20$  .
2. Carrier camber is within 1 mm in 250 mm.
3. Material : Black Conductive Polystyrene Alloy .
4. All dimensions meet EIA-481 requirements.
5. Thickness :  $0.30\pm 0.05$ mm.
6. Packing length per 22" reel : 378 Meters.(N=122 )
7. Component load per 13" reel : 1000 pcs.

Figure 11.3 SOW16/SOW14 Reel Information

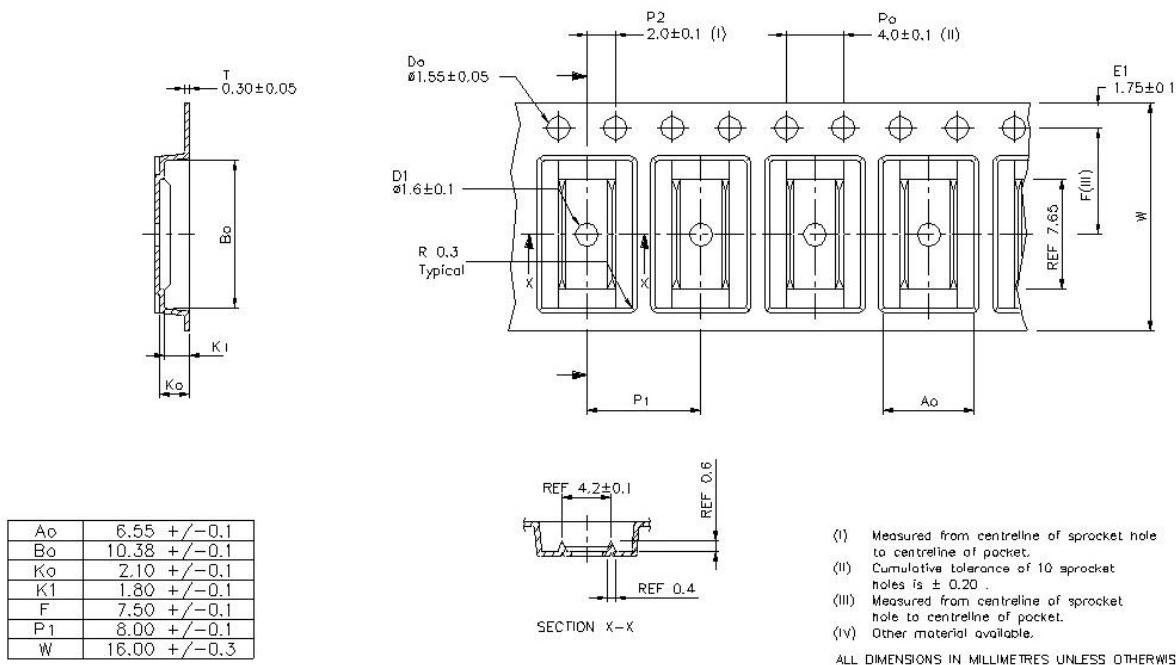


Figure 11.4 SOP16 Reel Information

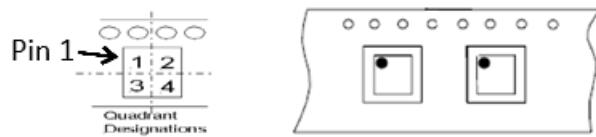


Figure 11.5 Quadrant Designation for Pin1 Orientation in Tape

## 12. Revision History

Revision	Description	Date
1.0	Initial version	2021/3/12
1.1	Increase SOP16 and LGA13 packages information.	2021/8/18